

Date: Apr. 15, 2015

Description of change

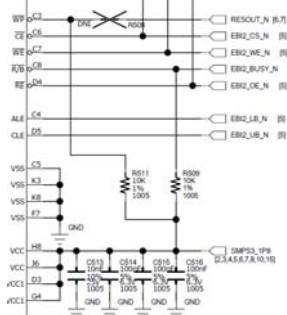
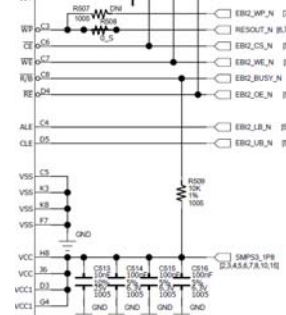
FCC ID : YZP-VL1000

Base Model : LTD-VL1000

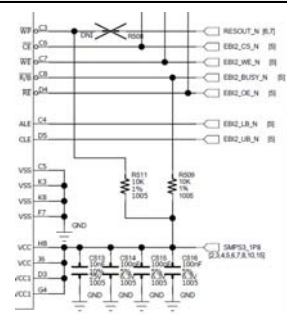
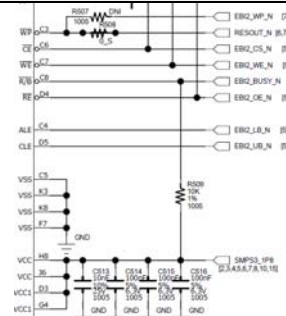
Variation Model : LTD-VL1110, LTD-VL1200

I inform that modules of between above models has minor change.

The differences between LTD-VL1000 and LTD-VL1110 are memory and changed resisters in below table.

LTD-VL1110	LTD-VL1000	Description of changes
S34MS02G200BHI00 (SPANSION, 2G NAND)	S34MS01G200BHI00 (SPANSION, 1G NAND)	Memory change (1G→2G)
		Add the Pull-up resistor (R511) for stabilization of the NAND memory.
Removed the R507	DNI	For System stabilization

The difference between LTD-VL1000 and LTD-VL1200 is changed resisters in below table.

LTD-VL1200	LTD-VL1000	Description of changes
		Add the Pull-up resistor (R511) for stabilization of the NAND memory.
Removed R507	DNI	For System stabilization

Exclude above description of changes, other part is same between LTD-VL1000 and LTD-VL1110, LTD-VL1200.

Sincerely,



Jeong Inchang
 Senior Research Engineer